

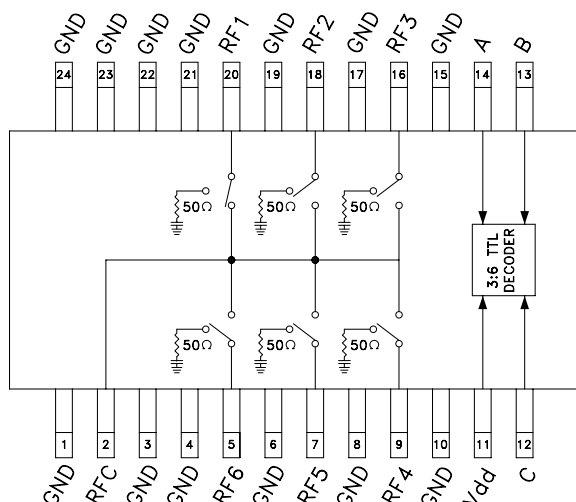
## GaAs MMIC SP6T NON-REFLECTIVE SWITCH, DC - 3.0 GHz

### Typical Applications

The HMC252QS24 is ideal for:

- Base Station
- CATV / DBS
- MMDS & WirelessLAN
- Test Equipment

### Functional Diagram



### Features

- Low Insertion Loss (2 GHz): 0.9 dB
- Single Positive Supply:  $V_{dd} = +5V$
- Integrated 3:6 TTL Decoder
- 24 Lead QSOP Package

### General Description

The HMC252QS24 is a low-cost non-reflective SP6T switch in a 24-lead QSOP package featuring wideband operation from DC to 3.0 GHz. The switch offers a single positive bias and true TTL/CMOS compatibility. A 3:6 decoder is integrated on the switch requiring only 3 control lines and a positive bias to select each path. The HMC252QS24 SP6T replaces multiple configurations of SP4T and SPDT MMIC switches and logic drivers.

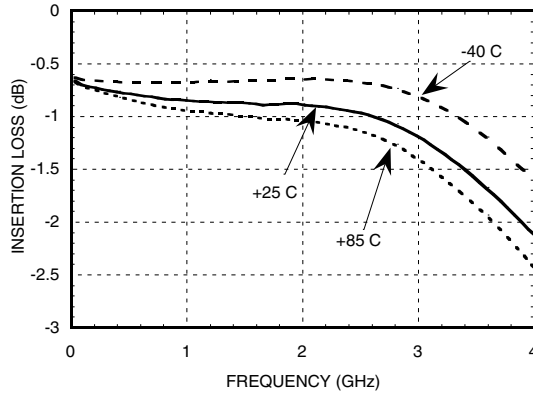
### Electrical Specifications,

$T_A = +25^\circ C$ , For TTL Control and  $V_{dd} = +5V$  in a 50 Ohm System

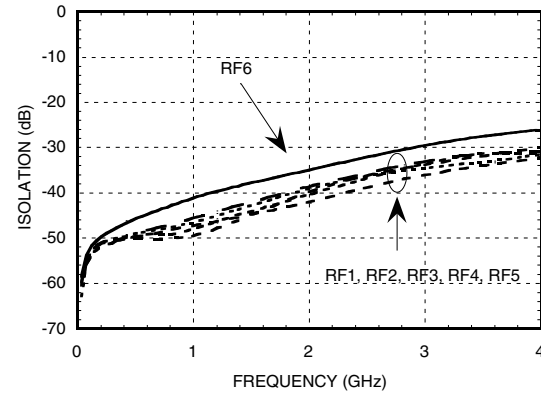
| Parameter                                                                | Frequency         | Min.                             | Typ. | Max. | Units |
|--------------------------------------------------------------------------|-------------------|----------------------------------|------|------|-------|
| Insertion Loss                                                           | DC - 1.0 GHz      |                                  | 0.8  | 1.2  | dB    |
|                                                                          | DC - 2.0 GHz      |                                  | 0.9  | 1.3  | dB    |
|                                                                          | DC - 2.5 GHz      |                                  | 1.0  | 1.5  | dB    |
|                                                                          | DC - 3.0 GHz      |                                  | 1.3  | 1.8  | dB    |
| Isolation                                                                | DC - 1.0 GHz      | 38                               | 41   |      | dB    |
|                                                                          | DC - 2.0 GHz      | 32                               | 35   |      | dB    |
|                                                                          | DC - 2.5 GHz      | 29                               | 32   |      | dB    |
|                                                                          | DC - 3.0 GHz      | 26                               | 29   |      | dB    |
| Return Loss                                                              | "On State"        | DC - 2.5 GHz                     | 14   | 18   | dB    |
|                                                                          |                   | DC - 3.0 GHz                     | 7    | 12   | dB    |
| Return Loss                                                              | RF1-6 "Off State" | 0.3 - 3.0 GHz                    | 8    | 12   | dB    |
|                                                                          |                   | 0.5 - 2.5 GHz                    | 11   | 15   | dB    |
| Input Power for 1dB Compression                                          | 0.3 - 3.0 GHz     | 21                               | 24   |      | dBm   |
| Input Third Order Intercept<br>(Two-Tone Input Power = +7 dBm Each Tone) | 0.3 - 3.0 GHz     | 42                               | 46   |      | dBm   |
| Switching Characteristics                                                | 0.3 - 3.0 GHz     |                                  |      |      |       |
|                                                                          |                   | tRISE, tFALL (10/90% RF)         | 35   |      | ns    |
|                                                                          |                   | tON, tOFF (50% CTL to 10/90% RF) | 120  |      | ns    |

## GaAs MMIC SP6T NON-REFLECTIVE SWITCH, DC - 3.0 GHz

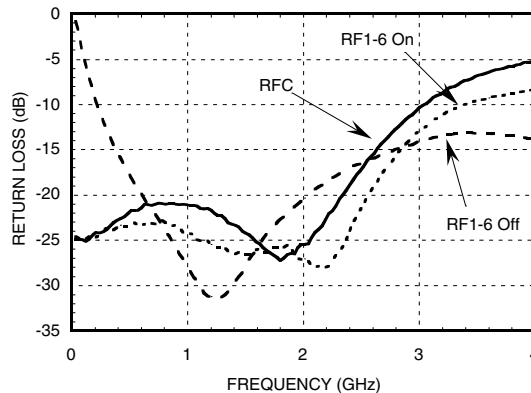
### Insertion Loss



### Isolation



### Return Loss



### Bias Voltage & Current

| Vdd Range = +5.0 Vdc ± 10% |                 |                 |
|----------------------------|-----------------|-----------------|
| Vdd (Vdc)                  | Idd (Typ.) (mA) | Idd (Max.) (mA) |
| +5.0                       | 5.0             | 8.0             |

### TTL/CMOS Control Voltages

| State | Bias Condition                |
|-------|-------------------------------|
| Low   | 0 to +0.8 Vdc @ 5uA Typ.      |
| High  | +2.0 to +5.0 Vdc @ 70 uA Typ. |

### Truth Table

| Control Input |      |      | Signal Path State |
|---------------|------|------|-------------------|
| A             | B    | C    | RFCOM to:         |
| LOW           | LOW  | LOW  | RF1               |
| HIGH          | LOW  | LOW  | RF2               |
| LOW           | HIGH | LOW  | RF3               |
| HIGH          | HIGH | LOW  | RF4               |
| LOW           | LOW  | HIGH | RF5               |
| HIGH          | LOW  | HIGH | RF6               |
| LOW           | HIGH | HIGH | ALL OFF           |
| HIGH          | HIGH | HIGH | ALL OFF           |

#### NOTE:

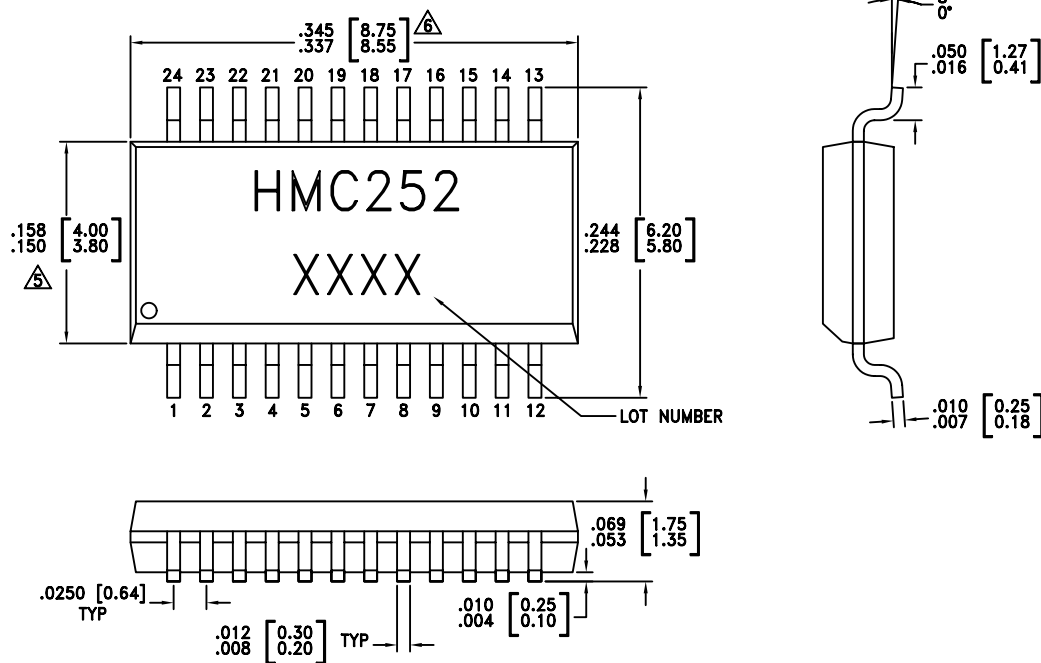
- DC Blocking capacitors are required at ports RFC and RF1, 2, 3, 4, 5, 6.
- Input is reflective when "ALL OFF" state is selected.

## GaAs MMIC SP6T NON-REFLECTIVE SWITCH, DC - 3.0 GHz

### Absolute Maximum Ratings

|                                          |                                                     |
|------------------------------------------|-----------------------------------------------------|
| Bias Voltage Range (Port Vdd)            | +7.0 Vdc                                            |
| Control Voltage Range (A, B, C)          | -0.5V to Vdd +1 Vdc                                 |
| Channel Temperature                      | 150 °C                                              |
| Thermal Resistance (Insertion Loss Path) | 240 °C/W                                            |
| Thermal Resistance (Terminated Path)     | 260 °C/W                                            |
| Storage Temperature                      | -65 to +150 °C                                      |
| Operating Temperature                    | -40 to +85 °C                                       |
| Maximum Input Power<br>Vdd = +5 Vdc      | +20 dBm (0.05 - 0.5 GHz)<br>+26 dBm (0.5 - 3.0 GHz) |

### Outline Drawing

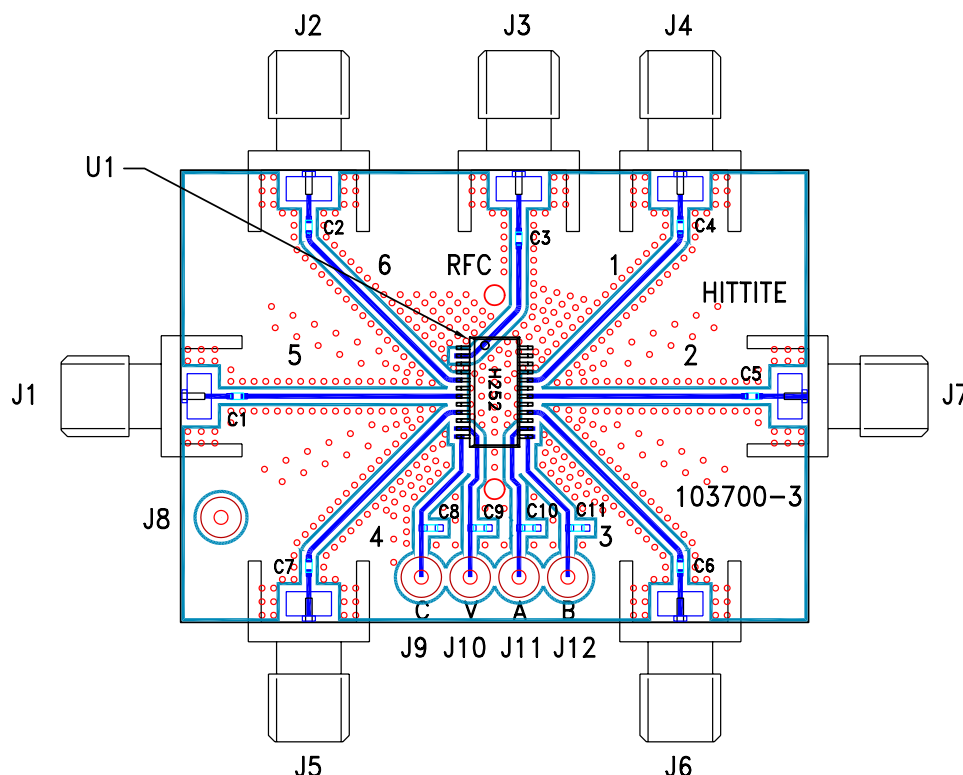


#### NOTES:

1. PACKAGE BODY MATERIAL: LOW STRESS INJECTION MOLDED PLASTIC SILICA AND SILICON IMPREGNATED.
2. LEADFRAME MATERIAL: COPPER ALLOY
3. LEADFRAME PLATING: Sn/Pb SOLDER
4. DIMENSIONS ARE IN INCHES [MILLIMETERS].
5. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
6. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
7. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

## GaAs MMIC SP6T NON-REFLECTIVE SWITCH, DC - 3.0 GHz

### Evaluation Circuit Board



The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF ports should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown above. A sufficient number of VIA holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.

### List of Material

| Item     | Description                    |
|----------|--------------------------------|
| J1 - J7  | PC Mount SMA Connector         |
| J8 - J12 | DC Pin                         |
| C1 - C7  | 100 pF Capacitor, 0402 Pkg.    |
| C8 - C11 | 10,000 pF Capacitor, 0603 Pkg. |
| U1       | HMC252QS24 SP8T Switch         |
| PCB*     | 103700 Eval Board              |

\* Circuit Board Material: Rogers 4350